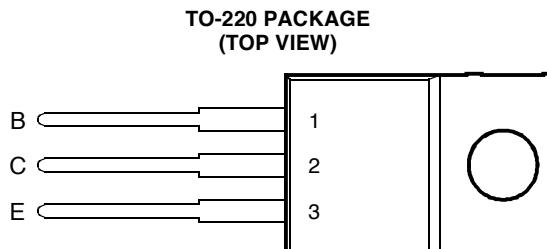


- 7 A Continuous Collector Current
- 15 A Peak Collector Current
- 60 W at 25°C Case Temperature

 This series is obsolete and not recommended for new designs.



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	BU406 BU407	V_{CBO}	400 330	V
Collector-emitter voltage ($V_{BE} = -2$ V)	BU406 BU407	V_{CEX}	400 330	V
Collector-emitter voltage ($I_B = 0$)	BU406 BU407	V_{CEO}	200 150	V
Emitter-base voltage		V_{EB}	6	V
Continuous collector current		I_C	7	A
Peak collector current (see Note 1)		I_{CM}	15	A
Continuous base current		I_B	4	A
Continuous device dissipation at (or below) 25°C case temperature		P_{tot}	60	W
Operating junction temperature range		T_j	-55 to +150	°C
Storage temperature range		T_{stg}	-55 to +150	°C

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	$I_C = 30 \text{ mA}$ $I_B = 0$			140			V
I_{CES}	$V_{CE} = 400 \text{ V}$	$V_{BE} = 0$	BU406			5	mA
	$V_{CE} = 330 \text{ V}$	$V_{BE} = 0$	BU407			5	
	$V_{CE} = 250 \text{ V}$	$V_{BE} = 0$	BU406			0.1	
	$V_{CE} = 200 \text{ V}$	$V_{BE} = 0$	BU407			0.1	
	$V_{CE} = 250 \text{ V}$	$V_{BE} = 0$	$T_C = 150^\circ\text{C}$	BU406		1	
	$V_{CE} = 200 \text{ V}$	$V_{BE} = 0$	$T_C = 150^\circ\text{C}$	BU407		1	
I_{EBO}	$V_{EB} = 6 \text{ V}$ $I_C = 0$					1	mA
h_{FE}	$V_{CE} = 10 \text{ V}$	$I_C = 4 \text{ A}$	(see Notes 2 and 3)	12			
	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$		20			
$V_{CE(sat)}$	$I_B = 0.5 \text{ A}$	$I_C = 5 \text{ A}$	(see Notes 2 and 3)			1	V
$V_{BE(sat)}$	$I_B = 0.5 \text{ A}$	$I_C = 5 \text{ A}$	(see Notes 2 and 3)			1.2	V
f_t	$V_{CE} = 5 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$	(see Note 4)	6		MHz
C_{ob}	$V_{CB} = 20 \text{ V}$	$I_E = 0$	$f = 1 \text{ MHz}$		60		pF

NOTES: 2. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.
 3. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.
 4. To obtain f_t the $[h_{FE}]$ response is extrapolated at the rate of -6 dB per octave from $f = 1 \text{ MHz}$ to the frequency at which $[h_{FE}] = 1$.

thermal characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta,JC}$	Junction to case thermal resistance			2.08	°C/W
$R_{\theta,JA}$	Junction to free air thermal resistance			70	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS [†]	MIN	TYP	MAX	UNIT
t_s	Storage time			2.7	μs
$t_{(off)}$	$I_C = 5 \text{ A}$ $I_{B(end)} = 0.5 \text{ A}$ (see Figures 1 and 2)			750	ns

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PARAMETER MEASUREMENT INFORMATION

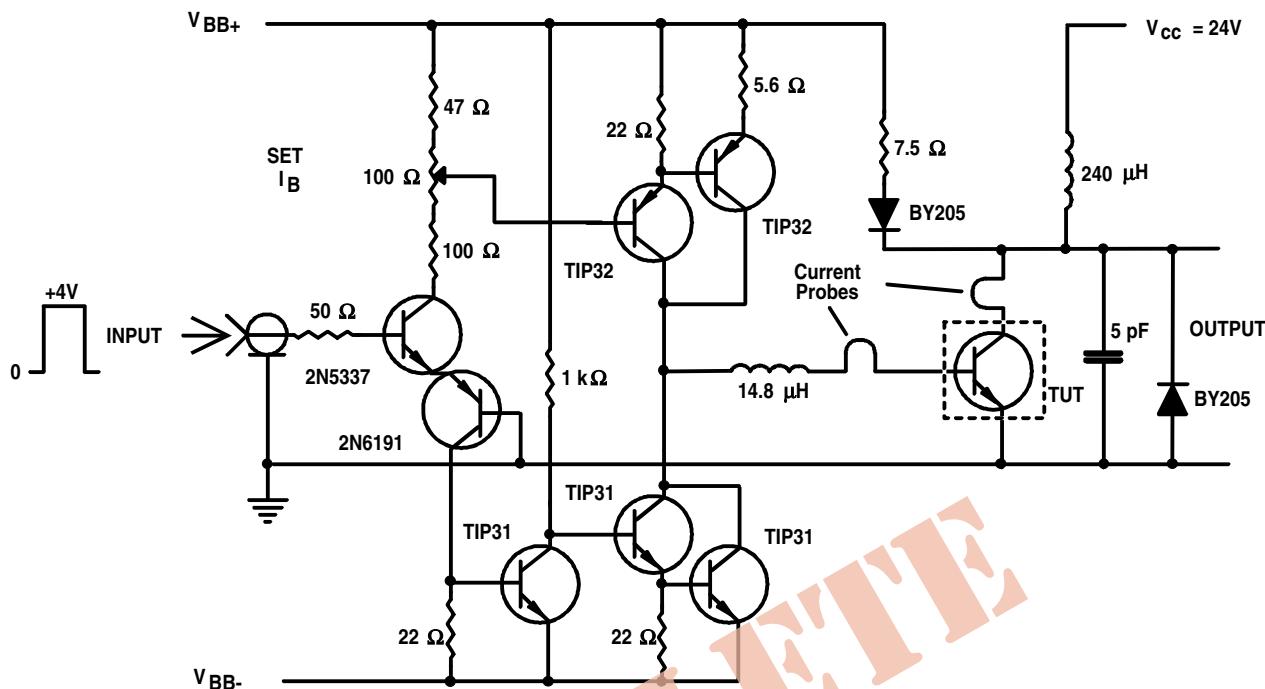


Figure 1. Inductive-Load Switching Test Circuit

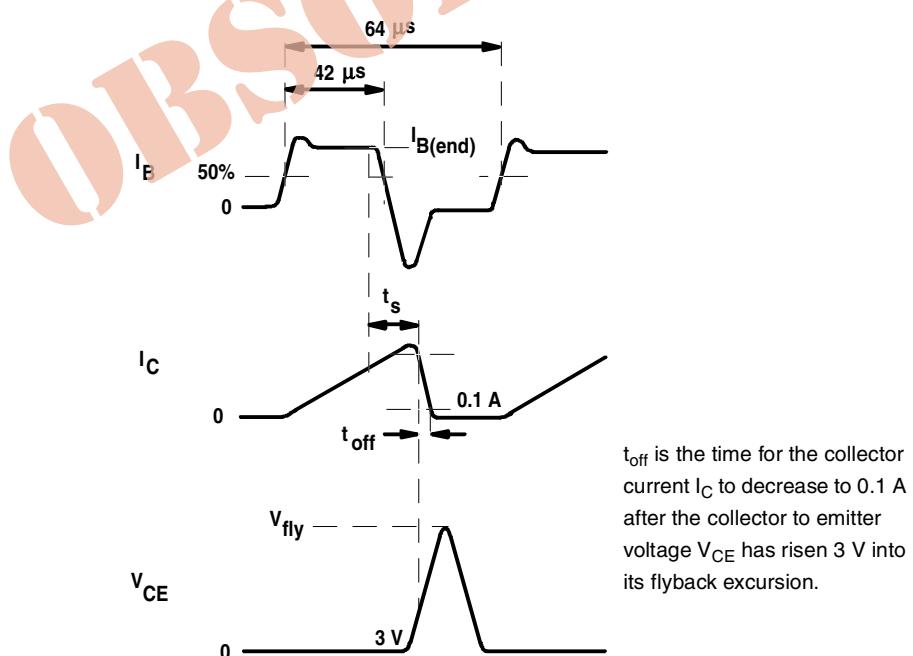


Figure 2. Inductive-Load Switching Waveforms

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

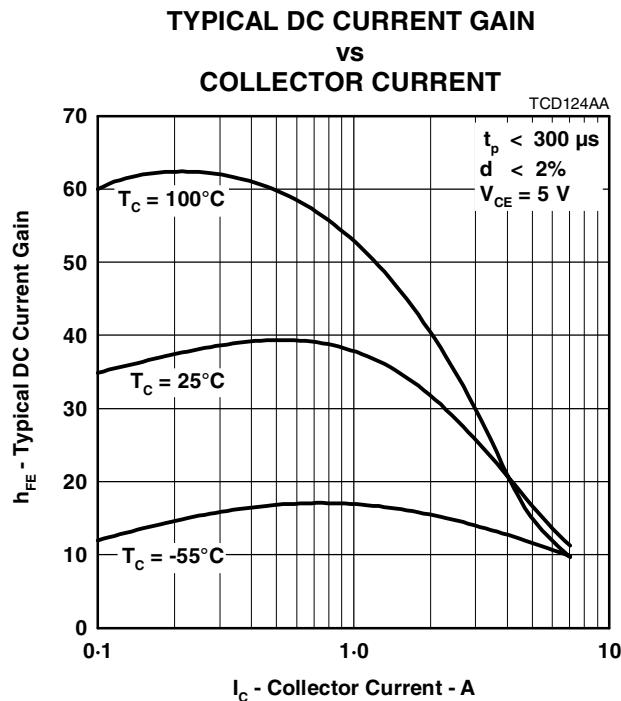


Figure 3.

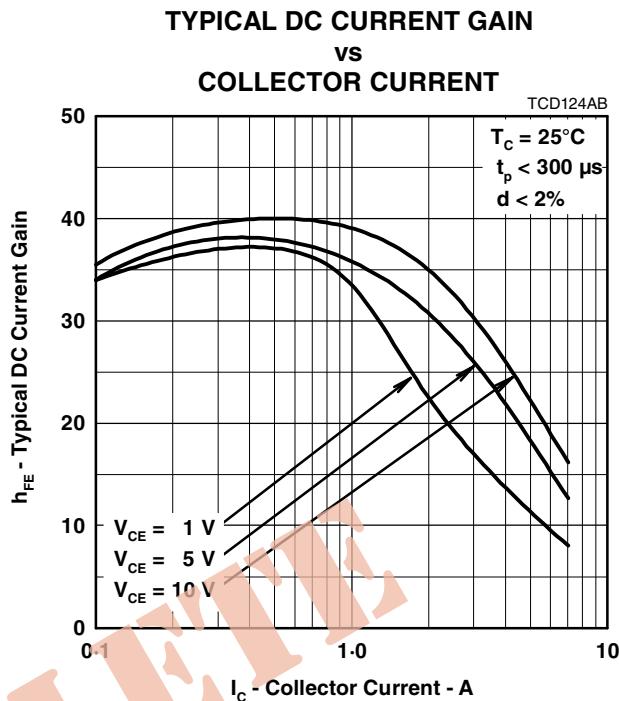


Figure 4.

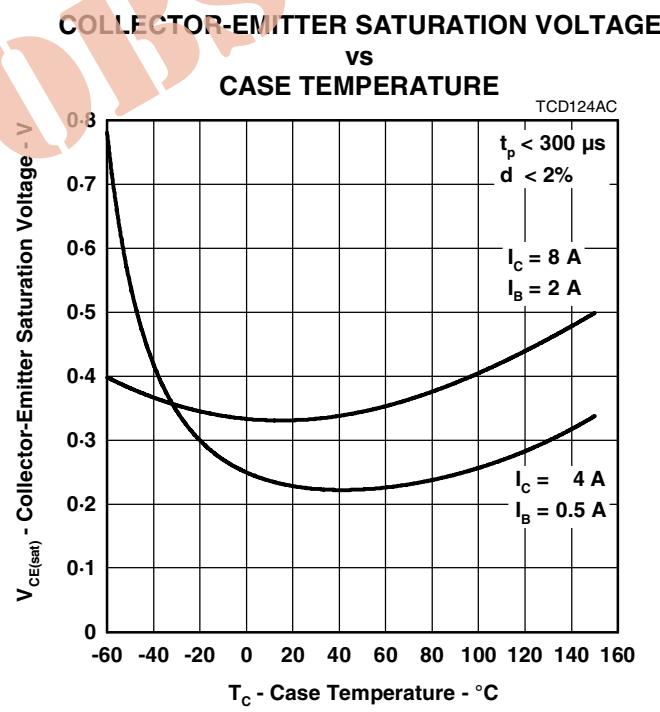


Figure 5.

PRODUCT INFORMATION

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MAXIMUM SAFE OPERATING REGIONS

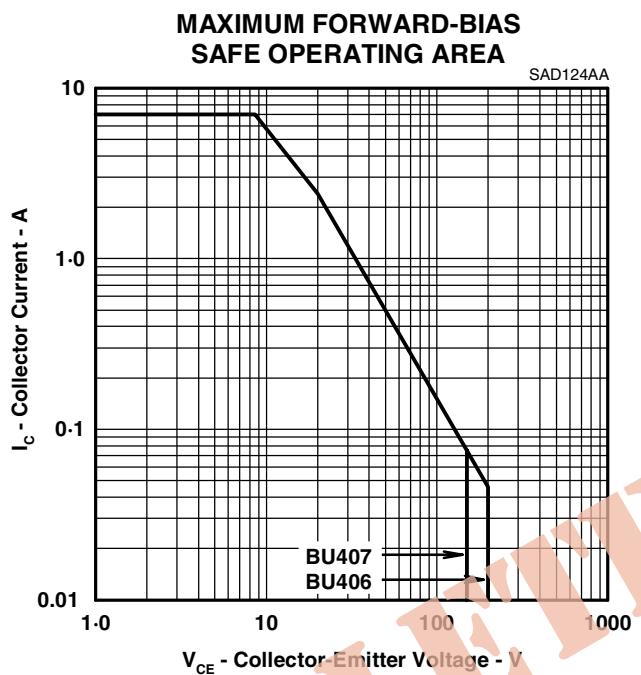


Figure 6.

PRODUCT INFORMATION

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